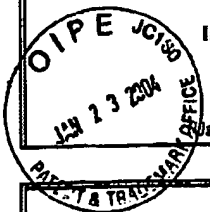


PTO-1449 REPRODUCED		ATTORNEY DOCKET NO. 3177.1000-000	APPLICATION NO. 09/863,013	
SUPPLEMENTAL INFORMATION DISCLOSURE CITATION IN AN APPLICATION January 21, 2004 (Use several sheets if necessary)		FIRST NAMED INVENTOR Milan R. Kokta		FILING DATE May 22, 2001
		EXAMINER Hung T. Vy	CONFIRMATION NO. 7269	GROUP 2828



U.S. PATENT DOCUMENTS

EXAM- INER INI- TIAL	REF. NO.	DOCUMENT NUMBER Number-Kind Code (if known)	ISSUE DATE / PUBLICATION DATE MM-DD-YYYY	NAME OF PATENTEE OR APPLICANT OF CITED DOCUMENT
la	AJ	3,883,313	05-13-1975	Cullen <i>et al.</i>
la	AK	4,627,064	12-02-1986	Auzel <i>et al.</i>
la	AA2	4,963,520	10-16-1990	Yoo <i>et al.</i>
la	AB2	5,530,267	06-25-1996	Brandle, Jr. <i>et al.</i>
la	AC2	6,104,529	08-15-2000	Brandle, Jr. <i>et al.</i>

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER Country Code-Number-Kind Code (if known)	DATE MM-DD-YYYY	NAME OF PATENTEE OR APPLICANT OF CITED DOCUMENT	TRANSLATION YES NO
la	AL	EP 0 148 656 A1	07-17-1985	Auzel <i>et al.</i>	

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la	AX4	Haisma, J., <i>et al.</i> , "Lattice-Constant-Adaptable Crystallographics," <i>Journal of Crystal Growth</i> , 102:979-993 (1990).
la	AY4	Nikishin, S.A., <i>et al.</i> , "Gas Source Molecular Beam Epitaxy of GaN with Hydrazine on Spinel Substrates," <i>Applied Science Letters</i> , American Institute of Physics, 72:2361-2363 (1998).
la	AZ4	Tamura, K., <i>et al.</i> , "Epitaxial Growth of ZnO Films on Lattice-Matched ScAlMgO ₄ (0001) Substrates," <i>Journal of Crystal Growth</i> , 214-215:59-62 (2000).
la	AR5	Wyon, C., <i>et al.</i> , "Czochralski Growth and Optical Properties of Magnesium-Aluminum Spinel Doped with Nickel," <i>Journal of Crystal Growth</i> , 79:710-713 (1986).

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EXAMINER <i>Leith AL-Nazer for Hung Vy</i>	DATE CONSIDERED <i>6/27/04</i>
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